LAMPIRAN E

DATASHEET

National Semiconductor

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LM35
Precision Centigrade Temperature Sensors

General Description

The LM35 series are precision integrated-circuit temperature sensors, whose output voltage is linearly proportional to the Celsius (Centigrade) temperature. The LM35 thus has an advantage over linear temperature sensors calibrated in ° Kelvin, as the user is not required to subtract a large constant voltage from its output to obtain convenient Centigrade scaling. The LM35 does not require any external calibration or trimming to provide typical accuracies of ±¼°C at room temperature and ±¾°C over a full −55 to +150°C temperature range. Low cost is assured by trimming and calibration at the wafer level. The LM35's low output impedance, linear output, and precise inherent calibration make interfacing to readout or control circuitry especially easy. It can be used with single power supplies, or with plus and minus supplies. As it draws only 60 µA from its supply, it has very low self-heating, less than 0.1°C in still air. The LM35 is rated to operate over a −55° to +150°C temperature range, while the LM35C is rated for a −40° to +110°C range (−10° with improved accuracy). The LM35 series is available packaged in hermetic TO-46 transistor packages, while the LM35C, LM35CA, and LM35D are also available in the plastic TO-92 transistor package. The LM35D is also available in an 8-lead surface mount small outline package and a plastic TO-220 package.

Features

- Calibrated directly in ° Celsius (Centigrade)
- Linear + 10.0 mV/°C scale factor
- 0.5°C accuracy guaranteeable (at +25°C)
- Rated for full −55° to +150°C range
- Suitable for remote applications
- Low cost due to wafer-level trimming
- Operates from 4 to 30 volts
- Less than 60 µA current drain
- Low self-heating, 0.08°C in still air
- Nonlinearity only ±¼°C typical
- Low impedance output, 0.1 Ω for 1 mA load

Typical Applications

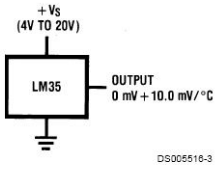
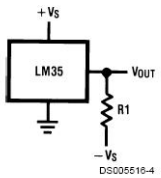


FIGURE 1. Basic Centigrade Temperature Sensor (+2°C to +150°C)

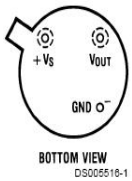


Choose $R_1 = -V_S/50\ \mu A$
V_{OUT} = +1,500 mV at +150°C
= +250 mV at +25°C
= −550 mV at −55°C

FIGURE 2. Full-Range Centigrade Temperature Sensor

Connection Diagrams

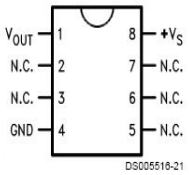
TO-46
Metal Can Package*



*Case is connected to negative pin (GND)

Order Number LM35H, LM35AH, LM35CH, LM35CAH or LM35DH
See NS Package Number H03H

SO-8
Small Outline Molded Package



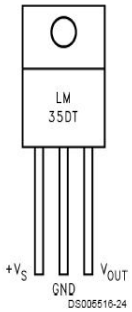
N.C. = No Connection

Top View
Order Number LM35DM
See NS Package Number M08A

TO-92
Plastic Package

Order Number LM35CZ, LM35CAZ or LM35DZ
See NS Package Number Z03A

TO-220
Plastic Package*



*Tab is connected to the negative pin (GND).
Note: The LM35DT pinout is different than the discontinued LM35DP.

Order Number LM35DT
See NS Package Number TA03F

Absolute Maximum Ratings (Note 10)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage	+35V to −0.2V
Output Voltage	+6V to −1.0V
Output Current	10 mA
Storage Temp.;	
TO-46 Package,	−60˚C to +180˚C
TO-92 Package,	−60˚C to +150˚C
SO-8 Package,	−65˚C to +150˚C
TO-220 Package,	−65˚C to +150˚C
Lead Temp.:	
TO-46 Package, (Soldering, 10 seconds)	300˚C
TO-92 and TO-220 Package, (Soldering, 10 seconds)	260˚C
SO Package (Note 12)	
Vapor Phase (60 seconds)	215˚C
Infrared (15 seconds)	220˚C
ESD Susceptibility (Note 11)	2500V
Specified Operating Temperature Range: T_{MIN} to T_{MAX} (Note 2)	
LM35, LM35A	−55˚C to +150˚C
LM35C, LM35CA	−40˚C to +110˚C
LM35D	0˚C to +100˚C

Electrical Characteristics

(Notes 1, 6)

Parameter	Conditions	LM35A			LM35CA			Units (Max.)
		Typical	Tested Limit (Note 4)	Design Limit (Note 5)	Typical	Tested Limit (Note 4)	Design Limit (Note 5)	
Accuracy	T_A=+25˚C	±0.2	±0.5		±0.2	±0.5		˚C
(Note 7)	T_A=−10˚C	±0.3			±0.3		±1.0	˚C
	T_A=T_{MAX}	±0.4	±1.0		±0.4	±1.0		˚C
	T_A=T_{MIN}	±0.4	±1.0		±0.4		±1.5	˚C
Nonlinearity (Note 8)	T_{MIN}≤T_A≤T_{MAX}	**±0.18**		**±0.35**	**±0.15**		**±0.3**	˚C
Sensor Gain (Average Slope)	T_{MIN}≤T_A≤T_{MAX}	**+10.0**	**+9.9, +10.1**		**+10.0**		**+9.9, +10.1**	mV/˚C
Load Regulation (Note 3) 0≤I_L≤1 mA	T_A=+25˚C	±0.4	±1.0		±0.4	±1.0		mV/mA
	T_{MIN}≤T_A≤T_{MAX}	**±0.5**		**±3.0**	**±0.5**		**±3.0**	mV/mA
Line Regulation (Note 3)	T_A=+25˚C	±0.01	±0.05		±0.01	±0.05		mV/V
	4V≤V_S≤30V	**±0.02**		**±0.1**	**±0.02**		**±0.1**	mV/V
Quiescent Current (Note 9)	V_S=+5V, +25˚C	56	67		56	67		µA
	V_S=+5V	**105**		**131**	**91**		**114**	µA
	V_S=+30V, +25˚C	56.2	68		56.2	68		µA
	V_S=+30V	**105.5**		**133**	**91.5**		**116**	µA
Change of Quiescent Current (Note 3)	4V≤V_S≤30V, +25˚C	0.2	1.0		0.2	1.0		µA
	4V≤V_S≤30V	**0.5**		**2.0**	**0.5**		**2.0**	µA
Temperature Coefficient of Quiescent Current		**+0.39**		**+0.5**	**+0.39**		**+0.5**	µA/˚C
Minimum Temperature for Rated Accuracy	In circuit of *Figure 1*, I_L=0	+1.5		+2.0	+1.5		+2.0	˚C
Long Term Stability	T_J=T_{MAX}, for 1000 hours	±0.08			±0.08			˚C

Electrical Characteristics

(Notes 1, 6)

Parameter	Conditions	LM35			LM35C, LM35D			Units (Max.)
		Typical	Tested Limit (Note 4)	Design Limit (Note 5)	Typical	Tested Limit (Note 4)	Design Limit (Note 5)	
Accuracy,	T_A=+25˚C	±0.4	±1.0		±0.4	±1.0		˚C
LM35, LM35C	T_A=−10˚C	±0.5			±0.5		±1.5	˚C
(Note 7)	T_A=T_{MAX}	±0.8	±1.5		±0.8		±1.5	˚C
	T_A=T_{MIN}	±0.8		±1.5	±0.8		±2.0	˚C
Accuracy, LM35D	T_A=+25˚C				±0.6	±1.5		˚C
(Note 7)	T_A=T_{MAX}				±0.9		±2.0	˚C
	T_A=T_{MIN}				±0.9		±2.0	˚C
Nonlinearity	T_{MIN}≤T_A≤T_{MAX}	**±0.3**		**±0.5**	**±0.2**		**±0.5**	˚C
(Note 8)								
Sensor Gain	T_{MIN}≤T_A≤T_{MAX}	**+10.0**	**+9.8, +10.2**		**+10.0**		**+9.8, +10.2**	mV/˚C
(Average Slope)								
Load Regulation	T_A=+25˚C	±0.4	±2.0		±0.4	±2.0		mV/mA
(Note 3) 0≤I_L≤1 mA	T_{MIN}≤T_A≤T_{MAX}	**±0.5**		**±5.0**	**±0.5**		**±5.0**	mV/mA
Line Regulation	T_A=+25˚C	±0.01	±0.1		±0.01	±0.1		mV/V
(Note 3)	4V≤V_S≤30V	**±0.02**		**±0.2**	**±0.02**		**±0.2**	mV/V
Quiescent Current	V_S=+5V, +25˚C	56	80		56	80		µA
(Note 9)	V_S=+5V	**105**		**158**	**91**		**138**	µA
	V_S=+30V, +25˚C	56.2	82		56.2	82		µA
	V_S=+30V	**105.5**		**161**	**91.5**		**141**	µA
Change of	4V≤V_S≤30V, +25˚C	0.2	2.0		0.2	2.0		µA
Quiescent Current	4V≤V_S≤30V	**0.5**		**3.0**	**0.5**		**3.0**	µA
(Note 3)								
Temperature Coefficient of Quiescent Current		**+0.39**		**+0.7**	**+0.39**		**+0.7**	µA/˚C
Minimum Temperature for Rated Accuracy	In circuit of *Figure 1*, I_L=0	+1.5		+2.0	+1.5		+2.0	˚C
Long Term Stability	T_J=T_{MAX}, for 1000 hours	±0.08			±0.08			˚C

Note 1: Unless otherwise noted, these specifications apply: −55˚C≤T_J≤+150˚C for the LM35 and LM35A; −40˚≤T_J≤+110˚C for the LM35C and LM35CA; and 0˚≤T_J≤+100˚C for the LM35D. V_S=+5Vdc and I_{LOAD}=50 µA, in the circuit of *Figure 2*. These specifications also apply from +2˚C to T_{MAX} in the circuit of *Figure 1*. Specifications in **boldface** apply over the full rated temperature range.

Note 2: Thermal resistance of the TO-46 package is 400˚C/W, junction to ambient, and 24˚C/W junction to case. Thermal resistance of the TO-92 package is 180˚C/W junction to ambient. Thermal resistance of the small outline molded package is 220˚C/W junction to ambient. Thermal resistance of the TO-220 package is 90˚C/W junction to ambient. For additional thermal resistance information see table in the Applications section.

Note 3: Regulation is measured at constant junction temperature, using pulse testing with a low duty cycle. Changes in output due to heating effects can be computed by multiplying the internal dissipation by the thermal resistance.

Note 4: Tested Limits are guaranteed and 100% tested in production.

Note 5: Design Limits are guaranteed (but not 100% production tested) over the indicated temperature and supply voltage ranges. These limits are not used to calculate outgoing quality levels.

Note 6: Specifications in **boldface** apply over the full rated temperature range.

Note 7: Accuracy is defined as the error between the output voltage and 10mv/˚C times the device's case temperature, at specified conditions of voltage, current, and temperature (expressed in ˚C).

Note 8: Nonlinearity is defined as the deviation of the output-voltage-versus-temperature curve from the best-fit straight line, over the device's rated temperature range.

Note 9: Quiescent current is defined in the circuit of *Figure 1*.

Note 10: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its rated operating conditions. See Note 1.

Note 11: Human body model, 100 pF discharged through a 1.5 kΩ resistor.

Note 12: See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" or the section titled "Surface Mount" found in a current National Semiconductor Linear Data Book for other methods of soldering surface mount devices.

LM358 (OpAmp)

FAIRCHILD SEMICONDUCTOR®

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LM2904,LM358/LM358A,LM258/ LM258A

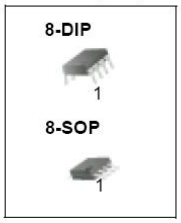
Dual Operational Amplifier

Features

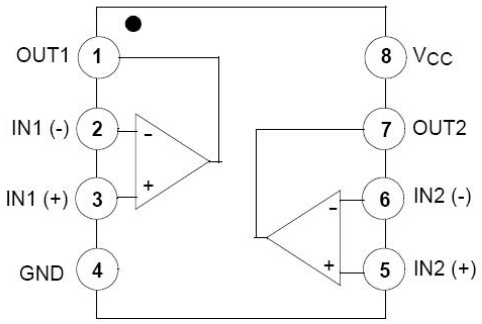
- Internally Frequency Compensated for Unity Gain
- Large DC Voltage Gain: 100dB
- Wide Power Supply Range:
  LM258/LM258A, LM358/LM358A: 3V~32V (or ±1.5V ~ 16V)
  LM2904 : 3V~26V (or ±1.5V ~ 13V)
- Input Common Mode Voltage Range Includes Ground
- Large Output Voltage Swing: 0V DC to Vcc -1.5V DC
- Power Drain Suitable for Battery Operation.

Description

The LM2904,LM358/LM358A, LM258/LM258A consist of two independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltage. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. Application areas include transducer amplifier, DC gain blocks and all the conventional OP-AMP circuits which now can be easily implemented in single power supply systems.

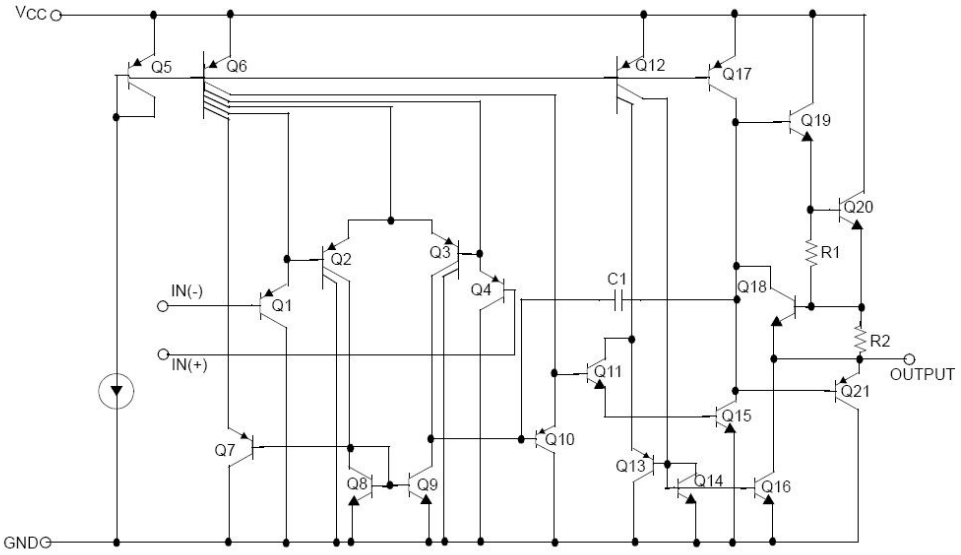


Internal Block Diagram



Schematic Diagram

(One section only)



Absolute Maximum Ratings

Parameter	Symbol	LM258/LM258A	LM358/LM358A	LM2904	Unit
Supply Voltage	V_{CC}	±16 or 32	±16 or 32	±13 or 26	V
Differential Input Voltage	$V_{I(DIFF)}$	32	32	26	V
Input Voltage	V_I	-0.3 to +32	-0.3 to +32	-0.3 to +26	V
Output Short Circuit to GND V_{CC}≤15V, T_A = 25°C(One Amp)	-	Continuous	Continuous	Continuous	-
Operating Temperature Range	T_{OPR}	-25 ~ +85	0 ~ +70	-40 ~ +85	°C
Storage Temperature Range	T_{STG}	-65 ~ +150	-65 ~ +150	-65 ~ +150	°C